

SOT-89 Plastic-Encapsulate Transistors

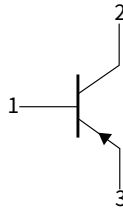
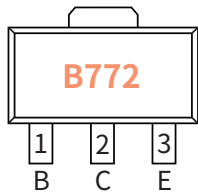
Features

- Low Saturation Voltage
- Power dissipation of 500mW
- High stability and high reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Mechanical Data

- Case: SOT-89
Molding compound meets UL 94V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Function Diagram



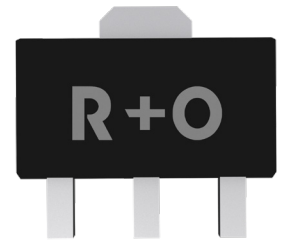
Collector-Base Voltage

V_{CBO} -40V

Collector Current

-3 Ampere

SOT-89



Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Collector-Base Voltage	V_{CBO}	V	-40
Collector-Emitter Voltage	V_{CEO}		-30
Emitter-Base Voltage	V_{EBO}		-6.0
Collector Current	I_C	A	-3.0
Collector Power Dissipation	P_C	mW	500
Storage temperature	T_{stg}	°C	-55 ~ +150
Junction temperature	T_j	°C	-55 ~ +150
Typical Thermal Resistance	$R_{\theta J-A}$	°C /W	250

Electrical Characteristics (Ta=25°C Unless otherwise noted)

PARAMETER	SYMBOL	UNIT	Condition	Min		Max
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	V	$I_C = -100\mu A, I_E = 0$	-40	—	—
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$		$I_C = -10mA, I_B = 0$	-30	—	—
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$		$I_E = -100\mu A, I_C = 0$	-6.0	—	—
Collector-Emitter cut-off current	I_{CEO}	μA	$V_{CE} = -30V, I_E = 0$	—	—	-10
Collector-Base cut-off current	I_{CBO}		$V_{CB} = -40V, I_E = 0$	—	—	-1.0
Emitter-Base cut-off current	I_{EBO}		$V_{EB} = -6.0V, I_C = 0$	—	—	-1.0
DC Current Gain	h_{FE}	V	$I_C = -1.0A, V_{CE} = -2.0V$	60	—	400
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V	$I_C = -2.0A, I_B = -0.2A$	—	—	-0.5
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	V	$I_C = -2.0A, I_B = -0.2A$	—	—	-1.5
Collector Output capacitance	C_{ob}	pF	$V_{CB} = -10V, I_E = 0, f = 1.0MHz$	—	35	—

● Classification Of h_{FE}

RANK	R	O	Y	GR
Range	60-120	100-200	160-320	200-400

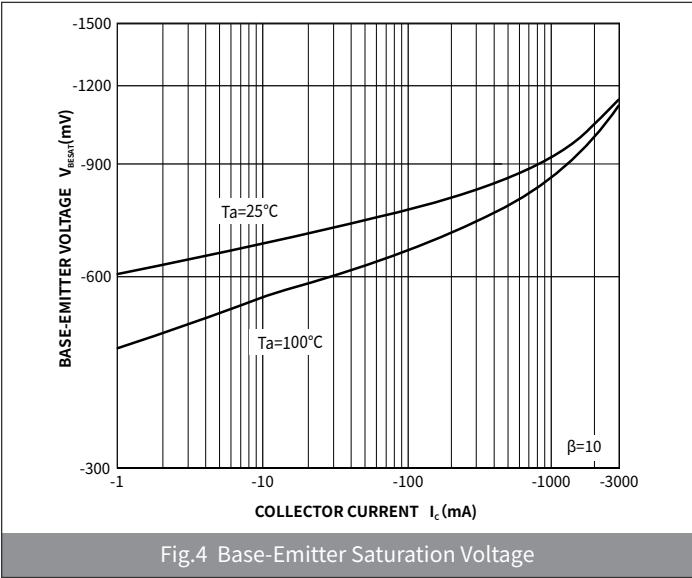
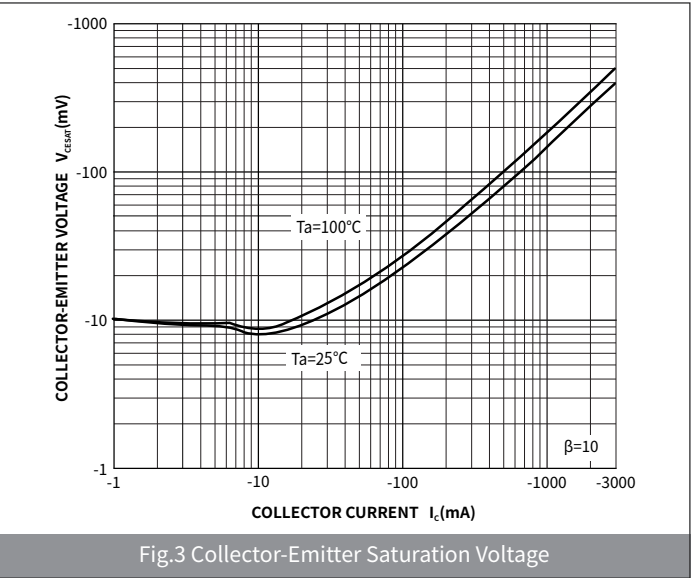
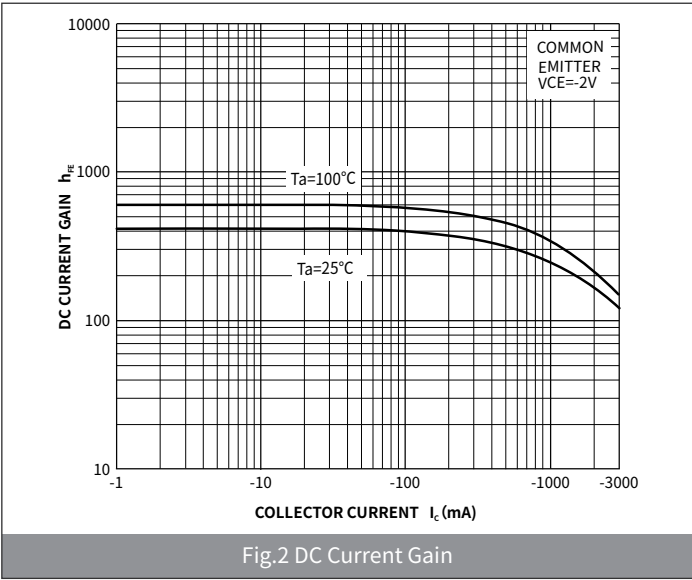
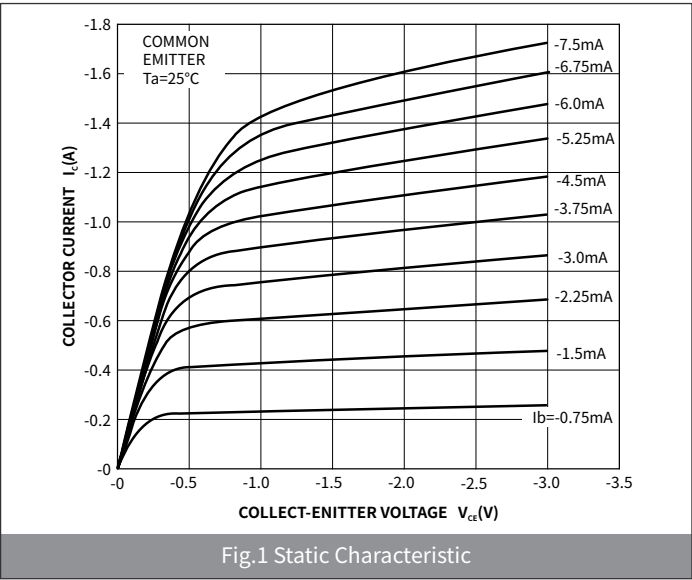
● Small-signal Characteristics

ITEM	SYMBOL	Condition	UNIT	Min	Tye	Max
Transition frequency	f_T	$I_C = -100\text{mA}$, $V_{CE} = -5.0\text{V}$	MHz	—	80	—

● Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-89	R1	0.055	1000	7000	21000	7"

● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



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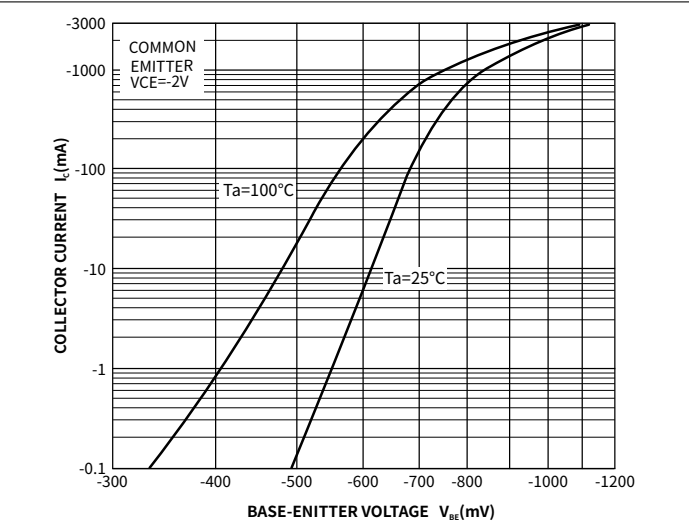


Fig.5 Base-Emitter On Voltage

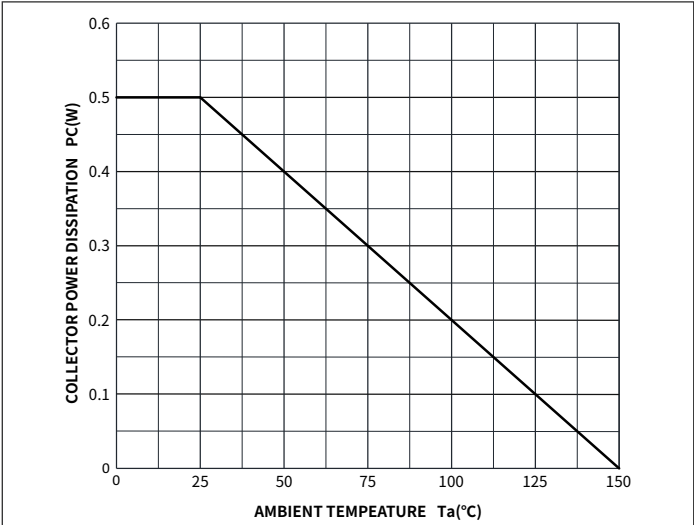
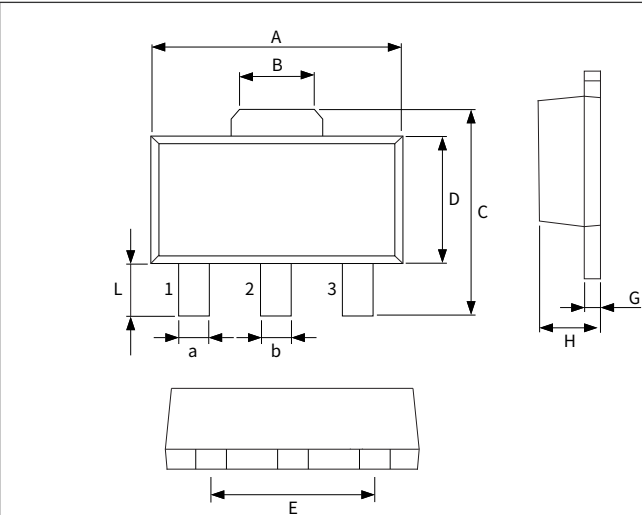


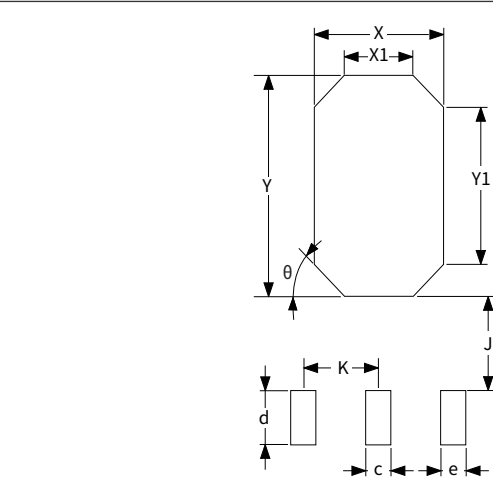
Fig.6 Power Derating Curve

● Package Outline Dimensions (SOT-89)



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.176	0.184
B	1.6	1.8	0.064	0.072
C	3.9	4.1	0.156	0.164
D	2.4	2.6	0.096	0.104
E	2.9	3.1	0.116	0.124
a	0.41	0.43	0.0164	0.018
b	0.35	0.45	0.014	0.018
L	0.95	1.05	0.037	0.041
G	0.3	0.5	0.012	0.020
H	1.4	1.5	0.055	0.059

● Suggested Pad Layout



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
c	0.80	1.00	0.032	0.04
d	1.30	1.50	0.052	0.060
e	0.70	0.90	0.028	0.036
J	1.80	2.00	0.072	0.080
K	1.40	1.60	0.056	0.064
X	2.50	2.70	0.100	0.108
X1	1.30	1.50	0.052	0.060
Y	4.30	4.50	0.172	0.180
Y1	3.10	3.30	0.124	0.132
θ	-	45°	-	45°